



Organic Semiconductors (OSC) p-Type Organic Semiconductors

Organic field-effect transistors (OFETs) have been good attentions as mechanically flexible and lightweight materials. Printed flexible devices for active layer made from organic semiconductor materials can be manufactured by means of low-cost and environment-friendly coating processes, and are particularly expected as next-generation electronics.

A newly line-up of highly soluble p-type semiconductor materials with high hole mobility is available from FUJIFILM Wako. These products are new materials developed by the joint research with Prof. Dr. Takeya and Assoc. Prof. Dr. Okamoto of The University of Tokyo and FUJIFILM Corporation.

Features

High hole mobility

The hall mobility is over 5 cm²/Vs.
High heat resistance
The products do not deteriorate even when used at the temperature required for OSC patterning.
High solubility
Solubility in toluene : 0.5 wt%

High repeatability

Good repeatability was confirmed in the characterization of the transistor by Pi-Crystal, Inc.

Sublimated products

The purity of over 99% is guaranteed



Summary of various transistor element characteristics

Film production method	Substrate temperature (°C)	µ _{max} (cm²/Vs)ª	V _{th} (V)⁵	I _{on} /I _{off}
Drop-casting	40	4.0	-21 — -37	10 ⁶
Edge-casting	40	6.2	-15 — -20	10 ⁶
Vacuum deposition	60 100	1.8 1.0	-15 — -20 -15 — -20	10 ⁶ 10 ⁶





The solvent evaporates from around the droplet

Edge-casting



The solvent evaporates towards the solution holding substrate

a) Evaluated in the saturation region. b) The gate insulator is SiO₂ with a thickness of 200 nm.

Product list



Product Number	Product Name	Package Size	Price
208-20821	TBBT-C ₄	100mg	List Price 750.00 USD
205-20831	TBBT-C ₁₀	100mg	List Price 750.00 USD

- References
 - Okamoto, T. and Takeya, J. et al.: Adv. Mater., 25, 6392 (2013).
 - Okamoto, T. et al.: J. Mater. Chem. C, 5, 1903 (2017).

Crystal film fabrication by edge casting method and transistor characterization evaluation





TBBT-C₁₀









Output

-10 -20 -30 -40

VG: From -1.3e- 3 V

Drain Voltage [V]

-50

0

Organic semiconductor building block product list

TBBT-H₂



TBBT-Br₂



Product Number	Product Name	Package Size	Price
204-20801	TBBT-H ₂	250mg	List Price 400.00 USD
201-20811	TBBT-Br ₂	250mg	List Price 450.00 USD

Listed products are intended for laboratory research use only, and not to be used for drug, food or human use. / Please visit our online catalog to search for other products from Wako; https://labchem-wako.fujifilm.com / This leaflet may contain products that cannot be exported to your country due to regulations. / Bulk quote requests for some products are welcomed. Please contact us.

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